

### **INFRARED EMITTING DIODE**

Part Number: KM2520SF4C03

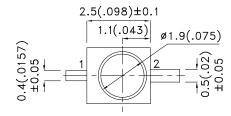
### **Features**

- SUBMINIA TURE PACKAGE.
- MECHANICALLY AND SPECTRALLY MATCHED TO THE PHOTOTRANSISTOR.
- GULL WING LEAD.
- LONG LIFE SOLID STATE RELIABILITY.
- LOW PACKAGE PROFILE.
- PACKAGE: 1000PCS/REEL.
- MOISTURE SENSITIVITY LEVEL: LEVEL 3.
- RoHS COMPLIANT.

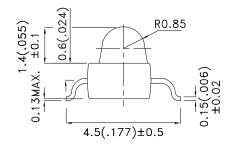
## Description

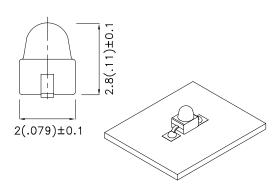
SF4 Made with Gallium Aluminum Arsenide Infrared Emitting diodes.

## **Package Dimensions**









- 1. All dimensions are in millimeters (inches).
  2. Tolerance is ±0.25(0.01") unless otherwise noted.
  3. Lead spacing is measured where the leads emerge from the package.
- Specifications are subject to change without notice.
   The device has a single mounting surface. The device must be mounted according to the specifications.





SPEC NO: DSAA5017 **REV NO: V.7 DATE: AUG/09/2007** PAGE: 1 OF 4 APPROVED: WYNEC **CHECKED: Allen Liu** DRAWN: Y.L.LI ERP: 1202000624

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## **Selection Guide**

Part No.	Dice	Lens Type	Po (mW/sr) [2] @ 20mA *50mA		Viewing Angle [1]
			Min.	Тур.	201/2
KM2520SF4C03	SF4 (GaAlAs)	WATER CLEAR	1.6	4	- 20°
			*2.6	*8	

- 1. 01/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value. 2. \* Luminous intensity with asterisk is measured at 50mA;Radiant Intensity/ luminous flux: +/-15%.

## Electrical / Optical Characteristics at TA=25°C

Parameter	P/N	Symbol	Тур.	Max.	Units	Test Conditions
Forward Voltage [1]	SF4	VF	1.3	1.6	V	IF=20mA
Reverse Current	SF4	lr		10	uA	VR = 5V
Capacitance	SF4	С	90		pF	VF=0V;f=1MHz
Peak Spectral Wavelength	SF4	λP	880		nm	IF=20mA
Spectral Bandwidth	SF4	Δλ1/2	50		nm	IF=20mA

Note: 1. Forward Voltage: +/-0.1V.

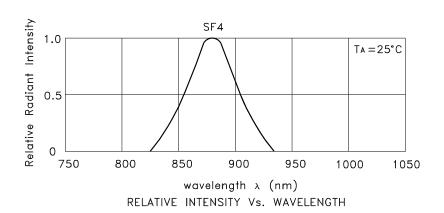
### Absolute Maximum Ratings at TA=25°C

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Parameter	Symbol	SF4	Units			
Power dissipation	Рт	80	mW			
DC Forward Current	lF	50	mA			
Peak Forward Current [1]	iFS	1.2	Α			
Reverse Voltage	VR	5	V			
Operating Temperature	ТА	-40 To +85	°C			
Storage Temperature	Тѕтс	-40 To +85	°C			

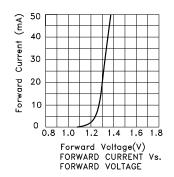
Note: 1. 1/100 Duty Cycle, 10µs Pulse Width.

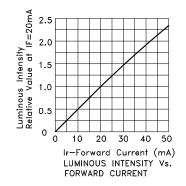
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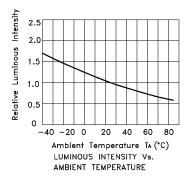
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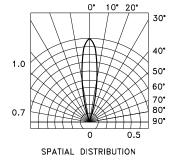


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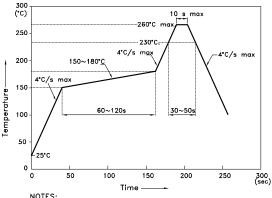
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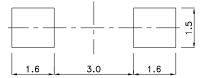
Reflow Soldering Profile For Lead-free SMT Process.



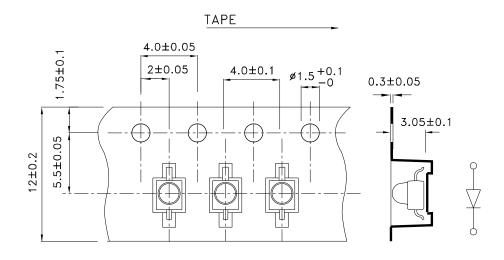
- NOTES:

  1.We recommend the reflow temperature 245°C(+/-5°C).The maximum soldering temperature should be limited to 260°C. 2.Don't cause stress to the epoxy resin while it is exposed to high temperature.
   3.Number of reflow process shall be 2 times or less.

**Recommended Soldering Pattern** (Units: mm; Tolerance: ± 0.1)



## **Tape Specifications** (Units: mm)



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